

Advance Information

Dual High-Side Switch 40 m Ω

The 33289 is a Dual High Side Switch (DHSS) dedicated for use in automotive applications. It is designed to drive typical inductive loads such as solenoid valves.

This device consists of two independent 40 m Ω R_{DSON} MOSFET channels plus corresponding control circuitry in a surface mount package. The 33289 can be interfaced directly to a microcontroller for input control and monitoring of diagnostic output.

Each switch offers independent protection and diagnosis during overcurrent, overvoltage, and undervoltage conditions, as well as an overtemperature shutdown feature.

A logic low on the Open Load Detect Enable pin (OLDE) minimizes bias current drain by disabling the open load circuitry current source. The device also has a very low quiescent current in standby mode.

FEATURES

- Designed to drive Automotive Inductive loads
- Operating Voltage Range from 6.0 V to 27 V
- Maximum Breakdown Voltage greater than 40 V
- 40 mΩ R_{DSON} at 25°C
- Overtemperature Protection with Hysteresis
- Overcurrent protection
- Under Voltage Shutdown
- Over Voltage Shutdown
- Open Load Detection in Off-State
- Independent Diagnostic Output
- ESD Protection 2.0 kV
- Standby Current less than 5.0 μA at V_{BAT} below 14 V



-40°C to 125°C

20 SOICW

				V _{PWR}		
	5.0 V	332	289	. ∓ _	L	
	_ ۲۹		VBAT			
		ST1	OUT1			ି
		ST2	OUT2		କା	3l
MCU	►	IN1			a∭	Ē
	┝──►	IN2	GND		Ŧ	
		OLDE		-		

MC33289DW/R2

Figure 1. 33289 Simplified Application Diagram

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33289



PIN CONNECTIONS





Table 1. Pin Function Description

Pin Number	Pin Name	Pin Function	Definition
1, 2, 5, 6, 15, 16, 19, 20	VBAT	Supply Voltage	These are the power supply pins of the device. These pins are directly connected with the lead frame of the package and are tied to the drain of the switching MOSFET. These pins can be directly connected to the battery voltage. In addition to their supply function, these pins participate to the thermal behavior of the device in conducting the heat from the switching MOSFET to the printed circuit board.
3, 4, 18, 17	OUT1	OUTPUT Channel 1	Pins 3 and 4 are the output 1 pins. Pins 17 and 18 are the output 2 pins. They are
	OUT2	OUTPUT Channel 2	directly connected to the source of the power MOSEE1. These pins are used by the control circuitry to sense the device output voltage. The R_{DSON} is 40 m Ω max per output at 25°C and will increase to a maximum of 75 m Ω at 150°C junction temperature.
8, 13	IN1	INPUT Channel 1	These are the device input pins which directly control their associated outputs.
	IN2	INPUT Channel 2	output MOSFET is in the off state. When input is high, the MOSFET is turned on and the load is activated.
			When both inputs are low, the device is in standby mode and its supply current is reduced. Each input pin has an internal active pull down, so that it will not float if disconnected.
9, 12	ST1	Status for Channel 1	These pins are the channel 1 and channel 2 fault detection flags. Their internal
	ST2	Status for Channel 2	structure is an open drain architecture with an internal clamp at 6.0 V. An external pull up resistor connected to V_{DD} (5.0 V) is needed. This is an active low output. If the device is in its normal condition the status lines will be high. If open load or other fault occurs, the associated channel status flag will be pulled low. See Functional Truth Table.
10	OLDE	Open Load Detection Enable	This pin is a digital input which enables the open load current diagnostic circuitry. When OLDE is a logic low, the open load circuitry is not powered and the device's bias current draw is at a minimum. If OLDE is a logic high, the open load circuitry is functional at the price of a higher bias current draw. OLDE pin has a pull down resistor.
11	GND	GROUND	This is the GND pin of the device.





Figure 3. Simplified Internal Block Diagram



ELECTRICAL CHARACTERISTICS

MAXIMUM RATINGS

Table 2. Maximum Ratings

All voltages are with respect to ground unless otherwise noted. Exceeding these ratings may cause a malfunction or permanent damage to the device.

Ratings	Symbol	Value	Unit
ELECTRICAL RATINGS			
V _{BAT} and V _{BATC} Voltage: Continuous/Pulse	V _{BAT}	-0.3 to 41	V
OUT1, OUT2 Voltage with Respect to GND: Continuous/Pulse	V _{OUT}	-4.0 to 41	V
OUT1, OUT2 to V _{BTAP} Voltage: Continuous	V _{OUT}	41	V
ST1, ST2 Voltage: Continuous/Pulse	V _{ST}	-0.3 to 7.0	V
IN1, IN2 Voltage: Continuous	V _{IN}	-0.3 to 7.0	V
IN1, IN2, ST1, ST2, OLDE Current	l _{iN}	+/-4.0	mA
ESD all Pins			
Human Body Model ⁽¹⁾	V _{ESD1}	+/-2000	V
Machine Model ⁽¹⁾	V _{ESD2}	+/-200	v
THERMAL RATINGS			
Operating Junction Temperature	TJ	-40 to 150	°C
Starage Temperature		551 450	

	• J	10 10 100	0
Storage Temperature	T _{ST}	-55 to 150	°C
Thermal Resistance Junction to Ambient ⁽²⁾	R _{THJA}	70	°C/W
Thermal Resistance Junction to lead: Both Channel on	R _{THJL1}	15	°C/W
Thermal Resistance Junction to lead: One Channel on	R _{THJL2}	15	°C/W
Thermal Resistance Junction to lead: Logic Die	R _{THJL3}	30	°C/W

Notes

1. EDS1 testing is performed in accordance with the Human Body Model (Czap = 100 pF, Rzap = 1500 Ω) EDS2 testing is performed in accordance with the Machine Model (Czap = 100 pF, Rzap = 0 Ω)

2. With minimum PCB dimensions.



STATIC ELECTRICAL CHARACTERISTICS

Table 3. Static Electrical Characteristics

Characteristics noted under conditions 7.0 V \leq V_{SUP} \leq 18 V, -40°C \leq T_A \leq 125°C, GND = 0 V unless otherwise noted. Typical values noted reflect the approximate parameter means at T_A = 25°C under nominal conditions unless otherwise noted.

Characteristic	Symbol	Min	Тур	Мах	Unit
POWER INPUT			I		
Operating Voltage	V _{BAT}	6.0		V _{OV}	V
Supply Current: Both Channels On	I _{BAT1}				mA
V _{BAT} = 13.5 V; OLDE High			6.0	16	
Supply Current: One Channel On	I _{BAT2}		5.0		mA
V _{BAT} = 13.5 V; OLDE High				10	
Supply Current: Both Channels Off	I _{BAT3}				μΑ
V _{BAT} = 12.6 V; OLDE Low, T _J < 125°C				5.0	
Supply Current: Any State	I _{BAT_MAX}				mA
V _{BAT} = 13.5 V				30	
Output Off state leakage current per channel	I _{DSS}				μA
V _{BAT} = 13.5 V; IN1, 2, OLDE low, Both output grounded,			0.1	5.0	
Tj < 125°C					
Drain-Source On Resistance	R _{DSON1}				mΩ
$V_{BAT} > 10 \text{ V}, \text{ I}_{AMB} = 25^{\circ}\text{C}$				40	
Drain-Source On Resistance	R _{DSON2}				mΩ
V _{BAT} > 10 V, T _{AMB} = 150°C				75	
Negative Inductive Clamp Voltage	V _{CLAMP}				V
I _{OUT} = 1 A		-4.0		-1.0	
INPUT CHARACTERISTICS					
High Input Voltage (IN1, IN2)	V _{IH}	3.25			V
High Input Voltage (OLDE)	V _{OLDEH}	3.5			V
Low Input Voltage (IN1, IN2, OLDE)	V _{IL}			1.5	V
Logic Input Hysteresis IN1, IN2	V _{HYST}	0.4	0.6	0.8	V
Logic Input Current	I _{IN}				μA
V _{IN} = 1.5 V		3.0			
Logic Input Current	I _{IN}				μA
V _{IN} = 3.25 V				32.5	
Logic Input Clamp Voltage	V _{CLMP}				V
At I _{IN} = 1 mA		5.5		7.0	
Input Capacitance IN1, IN2	C _{IN}				pF
R _{IN} = 47 kΩ @ 100 kHz				80	
STATUS CHARACTERISTICS	· ·				
Status Voltage	V _{ST}				V
I _{ST} = 1 mA; Output in fault	-			0.5	

I_{STLK}

10

μA

Status Leakage Current

 $V_{ST} = 5 V$

TRICAL CHARACTERISTICS

Table 3. Static Electrical Characteristics

Characteristics noted under conditions 7.0 V \leq V_{SUP} \leq 18 V, -40°C \leq T_A \leq 125°C, GND = 0 V unless otherwise noted. Typical values noted reflect the approximate parameter means at T_A = 25°C under nominal conditions unless otherwise noted.

Characteristic	Symbol	Min	Тур	Мах	Unit
Status Pin Capacitance	C _{ST}				pF
V _{ST} = 5 V				80	
OVERLOAD PROTECTION CHARACTERISTICS					
Overcurrent latchoff threshold	I _{OCT}				А
V _{BAT} = 13.5 V		4.0		9.0	
Thermal Shutdown	T _{SHUT}	150	165	175	°C
Thermal Shutdown Hysteresis	T _{HYST}			10	°C
Overvoltage Shutdown Threshold	V _{OV}				V
Both IN1, IN2 logic high		27		38	
Overvoltage Shutdown Hysteresis	V _{OVHYST}				V
Both IN1, IN2 logic high		0.1		2.0	
Undervoltage Shutdown Threshold	V _{UV}				V
Both IN1, IN2 logic high		4.75		6.0	
Undervoltage Shutdown Hysteresis	V _{UVHYST}				V
Both IN1, IN2 logic high		0.3	0.6	1.0	
OPEN CIRCUIT DETECTION CHARACTERISTICS					
Open Load Detect Current	I _{OL}				μA
V _{OUT} = 3.5 V, OLDE = 4.0 V		200	290	400	
Open Load Threshold Voltage	V _{OL}	1.5	2.4	3.5	V
Openload threshold voltage	V _{INOL}	1.5	2.5	3.5	V



DYNAMIC ELECTRICAL CHARACTERISTICS

Table 4. Dynamic Electrical Characteristics

Characteristics noted under conditions 7.0 V \leq V_{SUP} \leq 18 V, -40°C \leq T_A \leq 125°C, GND = 0 V unless otherwise noted. Typical values noted reflect the approximate parameter means at T_A = 25°C under nominal conditions unless otherwise noted.

Description	Symbol	Min	Тур	Max	Unit
OVERLOAD PROTECTION CHARACTERISTICS			•		<u>. </u>
Overcurrent latchoff delay From OverCurrent Treshold achieved to Output Voltage = 10% V _{BAT}	T _{OCTDLY}			30	μs
Overcurrent latchoff status delay From Output Voltage = 10% V _{BAT} to Status Flag <1 V	TOCTSTDLY			50	μs
OPEN CIRCUIT DETECTION CHARACTERISTICS					
Open Load to Status Low Delay Time From IN = 1.5 to Status Flag <1.5 V	T _{OLSTDT}			100	μs
Open Load Detect BlankingTime From IN = 1.5 to Openload circuitry enable	T _{OLDBT}	3.0	10	50	μs
SWITCHING CHARACTERISTICS ⁽³⁾					
Turn-on Slew Rate From 10% to V _{BAT} -3.0 V	S _{RPOUT1}	1.0		20	V/µs
Turn-on Slew Rate From V _{BAT} -3.0 V to 90%	S _{RPOUT2}	0.1		3.0	V/µs
Turn-off Slew Rate From 90% to 10%	S _{RNOUT}	1.0		20	V/µs
Turn-on Delay Time From V _{IN} /2 to 10% V _{BAT}	t _{DON}	1.0	2.5	15	μs
Turn-off Delay Time From V _{IN} /2 to 90% V _{BAT}	t _{DOFF}	1.0	5.0	15	μs
Notes 3. 8 V <v<sub>BAT <18 V, R_{LOAD} = 7 Ω</v<sub>		•			



TYPICAL APPLICATIONS



Figure 4. MC33289 Typical Application

Table 5. Functional Truth Table

Conditions	IN1	IN2	OUT1	OUT2	ST1	ST2
Normal Operating Conditions	L	L	L	L	Н	Н
	Н	L	Н	L	н	н
	L	Н	L	Н	Н	Н
	Н	Н	Н	Н	Н	Н
Overtemperature Channel 1	Н	х	L	Х	L	Н
Overtemperature Channel 2	х	н	х	L	Н	L
Overtemperature Channel 1/Channel 2	Н	Н	L	L	L	L
Open Load Channel 1	L	Х	Н	Х	L	Н
Open Load Channel 2	Х	L	Х	Н	Н	L
Overcurrent Channel 1	Н	Х	L	х	L	Н
Overcurrent Channel 2	Х	Н	Х	L	Н	L
Undervoltage Condition	Х	Х	L	L	Н	Н
Overvoltage Condition	Х	Х	L	L	Н	Н
L = 'Low level'; H = 'High level'; X = 'don't care	}	•		•		



PACKAGING

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REVISION HISTORY

REVISION	DATE	DESCRIPTION OF CHANGES
4.0	6/2006	 Implemented Revision History page Converted to Freescale format Updated to the prevailing form and style



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